



MJE3439G Information



For Reference Only

Part Number MJE3439G

Manufacturer ON Semiconductor

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single

Description TRANS NPN 350V 0.3A TO225AA

Package TO-225AA, TO-126-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









MJE3439G Specifications

Manufacturer Part Number	MJE3439G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-225AA, TO-126-3
Series	-
Transistor Type	NPN
Current - Collector (Ic) (Max)	300mA
Voltage - Collector Emitter Breakdown (Max)	350V
Vce Saturation (Max) @ Ib, Ic	500mV @ 4mA, 50mA
Current - Collector Cutoff (Max)	20μΑ
DC Current Gain (hFE) (Min) @ Ic, Vce	15 @ 20mA, 10V
Power - Max	15W
Frequency - Transition	15MHz
Operating Temperature	-65°C ~ 150°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-225AA, TO-126-3
Supplier Device Package	TO-225AA
	Report errors?

MJE3439G Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

MJE3439G Payment Methods





















MJE3439G Shipping Methods













If you have any question about MJE3439G, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com